UGN-3019T/U AND UGS-3019T/U LOW-COST HALL EFFECT DIGITAL SWITCHES

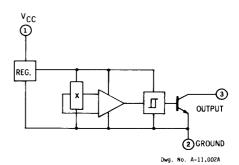
FEATURES

- 4.5 V to 24 V Operation
- Magnetically Driven Output
- High Reliability—No Moving Parts
- Small Size
- Output Compatible with All Digital Logic Families
- Constant Output Amplitude

ECONOMICAL TYPE 3019 Hall Effect integrated circuits provide fast, clean, and sure switching under demanding environmental conditions. The magnetically activated electronic devices are available with two operating temperature ranges and in two three-pin plastic packages.

Each Hall Effect circuit includes a voltage regulator, Hall voltage generator, signal amplifier, Schmitt trigger, and open-collector output on a single silicon chip. The on-board regulator permits operation over the supply-voltage range of 4.5 to 24 V.

The switches' open-collector outputs can sink up to 20 mA at a conservatively rated repetition rate of 100 kHz. They can be used directly with bipolar



FUNCTIONAL BLOCK DIAGRAM

or MOS logic circuits. Selected devices, with outputs capable of sinking 50 mA, are available on special order.

Types UGN-3019T and UGN-3019U are rated for operation over the temperature range of -20° C to $+85^{\circ}$ C. Types UGS-3019T and UGS-3019U have an operating range of -40° C to $+125^{\circ}$ C.

The Hall Effect switches are offered in two threepin plastic packages—a 60-mil (1.54 mm) magnetically optimized "U" package, and one 80 mils (2.03 mm) thick specified by the suffix "T."

ABSOLUTE MAXIMUM RATINGS

Supply Voltage, V _{cc}
Magnetic Flux Density, B
Output OFF Voltage
Output ON Current, I _{SINK}
Operating Temperature Range, T _A
UGN-3019T
UGN-3019U
UGS-3019T
UGS-3019U
Storage Temperature Range, T $_{s}$
UGN-3019T - 20°C to +85°C UGN-3019U - 20°C to +85°C UGS-3019T - 40°C to +125°C* UGS-3019U - 40°C to +125°C*

*Selected devices are available with a T_A range of -55° C to $+150^{\circ}$ C.

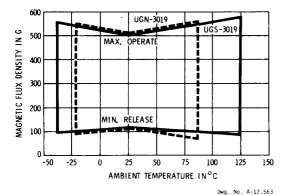
These Hall Effect sensors are also supplied in SOT 89 (TO-243AA) packages for surface-mount application. The regular SOT 89 package is specified by substituting an "LT" for the last character of the part number. The long leaded SOT 89 package is specified by substituting an "LL" for the last character of the part number and the Low profile "U" package is available by substituting "UA" for the last character of the part number (e.g., UGN-3XXXLT, UGN-3XXXLL, UGN-3XXXUA).

ELECTRICAL CHARACTERISTICS at $T_A = +25$ °C, $V_{cc} = 4.5$ V to 24 V (unless otherwise noted)

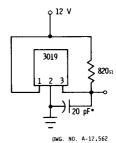
Characteristic	Symbol	Test Conditions	Min.	Тур.	Max.	Units
Operate Point*	B _{OP}		_	420	500	G
Release Point*	B _{RP}		125	300	_	G
Hysteresis*	B _H		50	120		G
Output Saturation Voltage	V _{CE(SAT)}	$B \ge 500 \text{G}, I_{\text{SIMK}} = 20 \text{mA}$	_	85	400	m۷
Output Leakage Current	l _{off}	$B \le 125 G, V_{OUT} = 24 V$		0.05	10	μΑ
Supply Current	I _{cc}	$B \le 125 \mathrm{G}, \mathrm{V}_{\mathrm{cc}} = 4.5 \mathrm{V}, \mathrm{Output} \mathrm{Open}$		2.3	5.0	mA
		$B \le 125 G$, $V_{cc} = 24 V$, Output Open		3.0	5.0	mA
Output Rise Time	t,	$V_{cc}=12$ V, $R_L=820\Omega$, $C_L=20$ pF		150		ns
Output Fall Time	t,	$ m V_{cc} = 12~V, R_L = 820\Omega, C_L = 20~pF$		400		ns

^{*}Magnetic flux density is measured at most sensitive area of device located at 0.036" ± 0.002" (0.91 mm ± 0.05 mm) below the branded face of the 'T' package and 0.016" ± 0.002" (0.41 mm ± 0.05 mm) below the branded face of the 'U' package.

GUARANTEED OPERATE AND RELEASE POINTS AS FUNCTIONS OF TEMPERATURE



TEST CIRCUIT



*Includes probe and test fixture capacitance.

0.086

2, 18

0.003 0.08

SENSOR-CENTER LOCATION

0. 089 2. 26 0. 050 1. 27 SQ.

PACKAGE OUTLINE
0.178 HIGH X 0.178 WIDE
4.52 X 4.52

VCC GND OUT

Dwg. No. A-12,399A

0, 0675

C OF CHIP

OPERATION

The most common modes of operation are headon and slide-by. As shown in the drawing at right, the magnet's polar axis is the centerline of the Hall Effect package. Change of operating states in the head-on mode is accomplished by decreasing or increasing the distance between the magnet and Hall cell.

The output transistor is OFF when the flux density of the magnetic field perpendicular to the surface of the chip is below threshold (the operate point). When flux density reaches the operate point, the output transistor switches ON and is capable of sinking 25 mA of current.

Note that the device is turned ON by presenting the south pole of the magnet to the branded face of the package, which is opposite the side with the ejector pin indentation. With the branded side facing you and the pins pointing down, pinouts are, from left to right: (1) $V_{\rm CC}$, (2) GND, (3) $V_{\rm OUT}$.

The output transistor is switched OFF when flux density of the magnetic field falls below the release point, which is less than the operate point. Hysteresis, as illustrated in the Transfer Characteristics graph, prevents ambiguity and oscillation.

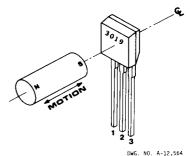
TOTAL EFFECTIVE AIR GAP

Type 3019 Hall Effect switches are offered in two packages, "T" and "U". The "U" package is about 0.020" (0.05 mm) thinner than the "T" package. The difference is found in the distance from the surface of the Hall cell to the branded face of the package: The active area depth. The "T" pack's active area depth is 0.036" (0.9 mm); the "U" pack's is 0.016" (0.4 mm).

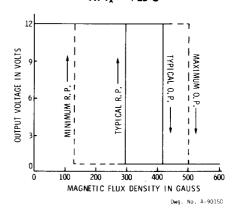
Total effective air gap is the sum of active area depth and the distance between the package's surface and the magnet's surface. The graph of Flux Density as a Function of Effective Air Gap illustrates the considerable increase in flux density at the sensor provided by the thinner package. The actual gain depends on the characteristic slope of flux density for a particular magnet.

A wide variety of magnets is commercially available. Each type of magnet exhibits unique magnetic field characteristics. The magnets used to construct the Flux Density graph were measured for the head-on mode of operation, but the graph's information is valid for peak flux density in the slide-by mode of switch activation.

HEAD-ON MODE

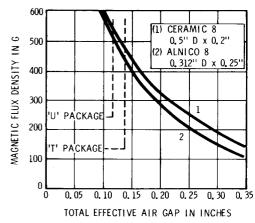


TRANSFER CHARACTERISTICS
AT T_A = +25°C



MAGNETIC FLUX DENSITY AS A FUNCTION OF TOTAL EFFECTIVE AIR GAP

Air Gap = 0.1''



DWG. NO. A-12,565